

## Radiation hardness of SiPMs

*Wednesday, 28 November 2018 09:00 (35 minutes)*

The current understanding of radiation tolerance of Silicon Photomultipliers (SiPMs) is reviewed. Effects of radiation damage caused by hadrons, electrons and gammas on SiPMs are presented and discussed. Ideas are presented on how to approach the development of radiation hard SiPMs for the future HEP experiments.

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